



Bipolar PNP Bare Die – BTP6901

Part Description

The BTP6901 is a silicon BJT transistor available in bare die form and well suited for use in general purpose switching and amplifier applications. NPN complement is BTN6901

Key Parameters:

- VCBO = -20V
- VCEO = -20V
- VEBO = -5V
- hFE = 220- @ VCE = -2V, IC = -0.5A
- VCE(Sat) = -0.21V @ IC = -2A, IB = -200mA
- fT = 100 MHz @ VCE = -5V, IE = 0A
- COBO = 50pF @ VCB = -10V

Features

Low VCE(sat). Designed to provide performance equivalent to NXP / NEXPERIA PBSS5320T

Die Size (Unawn)

810µm X 1150µm, 32 Mils X 45 Mils

This is a shortform datasheet only

For the full datasheet

Please contact sales@siliconsupplies.com

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